

## Low Power JFET Input Operational Amplifiers

These JFET input operational amplifiers are designed for low power applications. They feature high input impedance, low input bias current and low input offset current. Advanced design techniques allow for higher slew rates, gain bandwidth products and output swing. The LF441C device provides for the external null adjustment of input offset voltage.

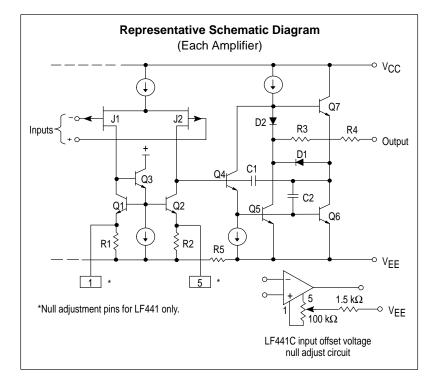
These devices are specified over the commercial temperature range. All are available in plastic dual in–line and SOIC packages.

Low Supply Current: 200 μA/Amplifier

Low Input Bias Current: 5.0 pA
High Gain Bandwidth: 2.0 MHz
High Slew Rate: 6.0 V/μs

High Input Impedance: 10<sup>12</sup> Ω
 Large Output Voltage Swing: ±14 V

Output Short Circuit Protection



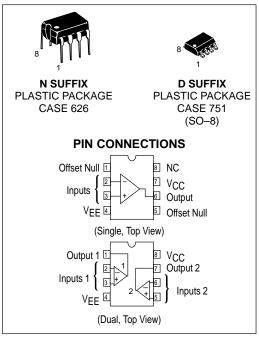
#### ORDERING INFORMATION

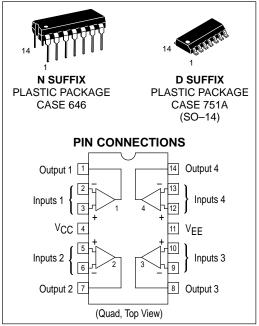
Device	Function	Operating Temperature Range	Package
LF441CD LF441CN	Single		SO-8 Plastic DIP
LF442CD LF442CN	Dual	$T_A = 0^\circ \text{ to } +70^\circ \text{C}$	SO-8 Plastic DIP
LF444CD LF444CN	Quad		SO-14 Plastic DIP

## LF441C LF442C LF444C

# LOW POWER JFET INPUT OPERATIONAL AMPLIFIERS

SEMICONDUCTOR TECHNICAL DATA





#### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Supply Voltage (from V <sub>CC</sub> to V <sub>EE</sub> )	٧s	+36	V
Input Differential Voltage Range (Note 1)	V <sub>IDR</sub>	±30	V
Input Voltage Range (Notes 1 and 2)	VIR	±15	V
Output Short Circuit Duration (Note 3)	tsc	Indefinite	sec
Operating Junction Temperature (Note 3)	TJ	+150	°C
Storage Temperature Range	T <sub>stg</sub>	-60 to +150	°C

- NOTES: 1. Differential voltages are at the noninverting input terminal with respect to the inverting input terminal.
  - 2. The magnitude of the input voltage must never exceed the magnitude of the supply
  - or 15 V, whichever is less.

    3. Power dissipation must be considered to ensure maximum junction temperature (T<sub>J</sub>) is not exceeded (see Figure 1).

### **DC ELECTRICAL CHARACTERISTICS** ( $V_{CC} = +15 \text{ V}$ , $V_{EE} = -15 \text{ V}$ , $T_A = 0^{\circ}$ to $70^{\circ}$ C, unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit
Input Offset Voltage (R <sub>S</sub> = 10 k $\Omega$ , V <sub>O</sub> = 0 V)	V <sub>IO</sub>				mV
Single: T <sub>A</sub> = +25°C		-	3.0	5.0	
$T_A = 0^\circ \text{ to } +70^\circ \text{C}$		_	_	7.5	
Dual: T <sub>A</sub> = +25°C		_	3.0	5.0	
$T_A = 0^{\circ} \text{ to } +70^{\circ}\text{C}$		_	_	7.5	
Quad: $T_A = +25^{\circ}C$		_	3.0	10	
T <sub>A</sub> = 0° to +70°C		_	_	12	
Average Temperature Coefficient of Offset Voltage $(R_S = 10 \text{ k}\Omega, V_O = 0 \text{ V})$	$\Delta V_{IO}/\Delta T$	_	10	_	μV/°C
Input Offset Current (V <sub>CM</sub> = 0 V, V <sub>O</sub> = 0 V)	lio				
T <sub>A</sub> = +25°C		_	0.5	50	pА
$T_A = 0^\circ \text{ to } +70^\circ \text{C}$		_	_	1.5	nA
Input Bias Current (V <sub>CM</sub> = 0 V, V <sub>O</sub> = 0 V)	I <sub>IB</sub>				
$T_A = +25^{\circ}C$	"	_	3.0	100	pА
$T_A = 0^\circ \text{ to } +70^\circ \text{C}$		-	_	3.0	nA
Common Mode Input Voltage Range (T <sub>A</sub> = +25°C)	VICR	_	+14.5	+11	V
	lon	-11	-12	-	
Large Signal Voltage Gain ( $V_O = \pm 10 \text{ V}, R_I = 10 \text{ k}\Omega$ )	Avol				V/mV
$T_A = +25$ °C	'02	25	60	_	
$T_A = 0^\circ \text{ to } +70^\circ \text{C}$		15	_	_	
Output Voltage Swing (R <sub>I</sub> = $10 \text{ k}\Omega$ )	Vo+	+12	+14	_	V
, , ,	Vo -	-	-14	-12	
Common Mode Rejection (R <sub>S</sub> $\leq$ 10 k $\Omega$ , V <sub>CM</sub> = V <sub>ICR</sub> , V <sub>O</sub> = 0 V)	CMR	70	86	-	dB
Power Supply Rejection (R <sub>S</sub> = 100 $\Omega$ , V <sub>CM</sub> = 0 V, V <sub>O</sub> = 0 V)	PSR	70	84	_	dB
Power Supply Current (No Load, V <sub>O</sub> = 0 V)	ID				μΑ
Single		_	200	250	
Dual		_	400	500	
Quad		_	800	1000	

AC ELECTRICAL CHARACTERISTICS ( $V_{CC}$  = +15 V,  $V_{EE}$  = -15 V,  $T_A$  = +25°C, unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit
Slew Rate ( $V_{in}$ = -10 V to +10 V, $R_L$ = 10 k $\Omega$ , $C_L$ = 10 pF, $A_V$ = +1.0)	SR	0.6	6.0	-	V/ μs
Settling Time To within 10 mV $(A_V = -1.0, R_L = 10 \text{ k}\Omega, V_O = 0 \text{ V to } +10 \text{ V})$ To within 1.0 mV	t <sub>S</sub>	- -	1.6 2.2	- -	μs
Gain Bandwidth Product (f = 200 kHz)	GBW	0.6	2.0	-	MHz
Equivalent Input Noise Voltage (R <sub>S</sub> = 100 Ω, f = 1.0 kHz)	e <sub>n</sub>	-	47	-	nV/√ <del>Hz</del>
Equivalent Input Noise Current (f = 1.0 kHz)	i <sub>n</sub>	-	0.01	-	pA/√Hz
Input Resistance	R <sub>i</sub>	-	1012	-	Ω
Channel Separation (f = 1.0 Hz to 20 kHz)	CS	_	120	_	dB

Figure 1. Maximum Power Dissipation versus Temperature for Package Variations

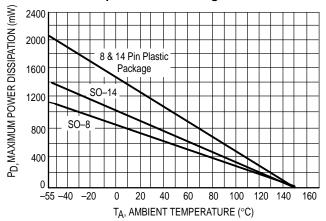


Figure 2. Input Bias Current versus Input Common Mode Voltage

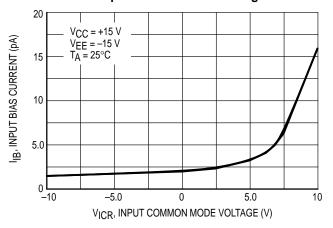


Figure 3. Input Bias Current versus Temperature

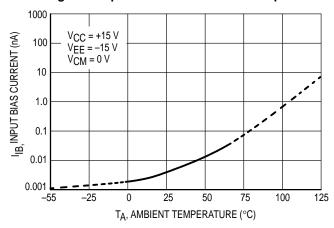


Figure 4. Supply Current versus Supply Voltage

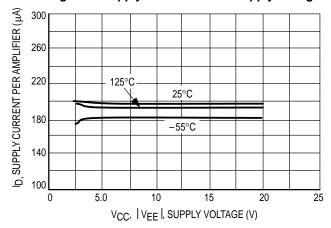


Figure 5. Positive Input Common Mode Voltage Range versus Positive Supply Voltage

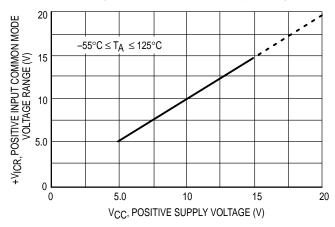


Figure 6. Negative Input Common Mode Voltage Range versus Negative Supply Voltage

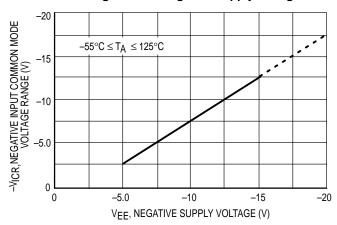


Figure 7. Output Voltage versus Output Source Current

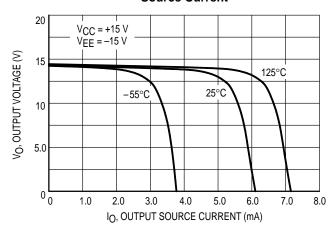


Figure 8. Output Voltage versus
Output Sink Current

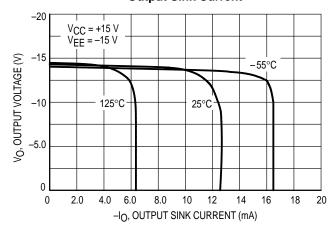


Figure 9. Output Voltage Swing versus Supply Voltage

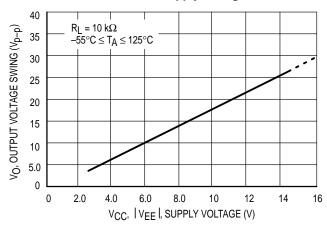


Figure 10. Output Voltage Swing versus Load Resistance

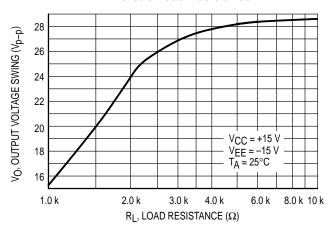
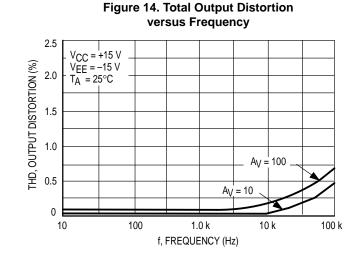


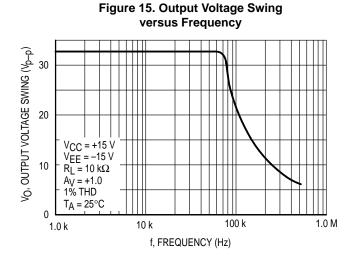
Figure 11. Normalized Gain Bandwidth **Product versus Temperature** GBW, NORMALIZED GAIN BANDWIDTH PRODUCT 1.4 V<sub>CC</sub> = +15 V V<sub>EE</sub> = -15 V R<sub>L</sub> = 10 kΩ 1.3  $C_{L}^{-} = 100 \text{ pF}$ 1.2 1.1 1.0 0.9 0.8 0.7 0.6 -50 25 -75 -25 0 50 75 100 125 TA, AMBIENT TEMPERATURE (°C)

**Phase versus Frequency** A<sub>VOL</sub>, OPEN LOOP VOLTAGE GAIN (dB) 90 φ, EXCESS PHASE (DEGREES) Phase 10 135 0 180 V<sub>CC</sub> = +15 V Gain VEE = -15 V 225  $R_L = 10 \text{ k}\Omega$   $C_L = 100 \text{ pF}$  $T_A = 25^{\circ}\dot{C}$ -20 270 0.1 1.0 10 f, FREQUENCY (MHz)

Figure 12. Open Loop Voltage Gain and

Figure 13. Slew Rate versus Temperature 8.0 SR, SLEW RATE (V/µs) 7.0 6.0 V<sub>CC</sub> = +15 V V<sub>EE</sub> = -15 V 5.0  $R_L = 10 \text{ k}\Omega$  $A_{V} = +1.0$ 4.0 --75 25 75 100 125 TA, AMBIENT TEMPERATURE (°C)





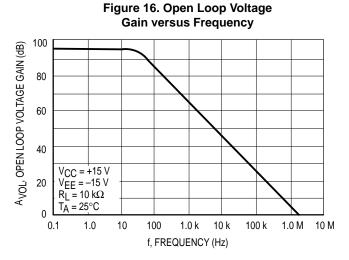


Figure 17. Common Mode Rejection versus Frequency

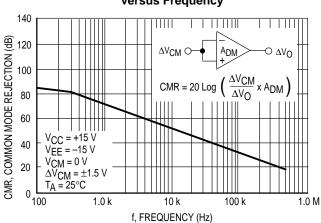


Figure 18. Power Supply Rejection versus Frequency

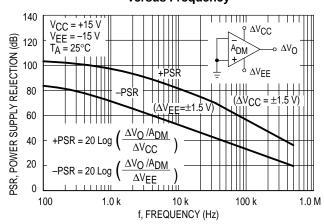


Figure 19. Input Noise Voltage versus Frequency

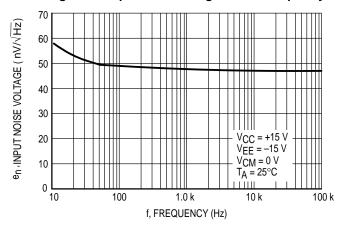


Figure 20. Open Loop Voltage Gain versus Supply Voltage

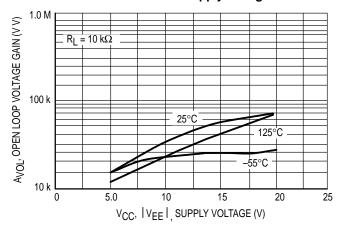


Figure 21. Output Impedance versus Frequency

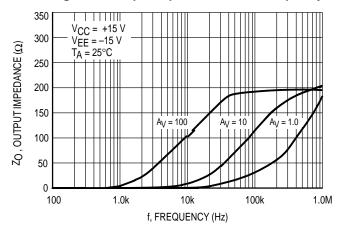
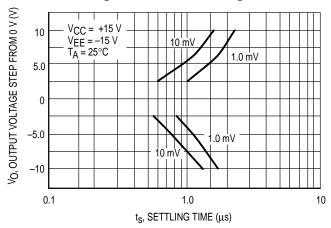


Figure 22. Inverter Settling Time

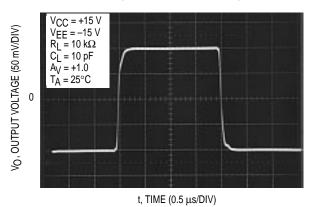


#### **SMALL SIGNAL RESPONSE**

Figure 23. Inverting

(NQ/M + 15 V) = -15 V VEE = -15 V  $R_L = 10 k\Omega$   $C_L = 10 pF$  AV = -1.0  $T_A = 25 °C$   $t, TIME (0.5 \mu s/DIV)$ 

Figure 24. Noninverting



#### LARGE SIGNAL RESPONSE

Figure 25. Inverting

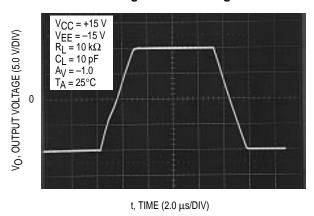
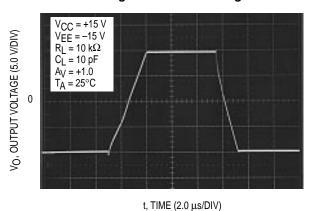
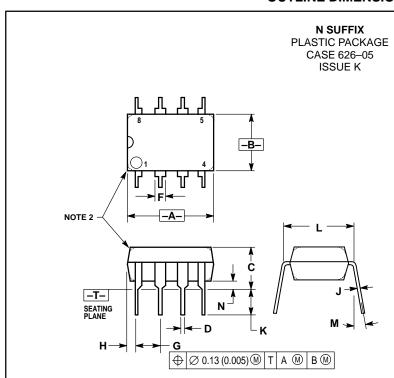


Figure 26. Noninverting



#### **OUTLINE DIMENSIONS**



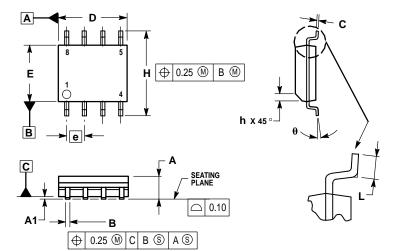
- NOTES:

  1. DIMENSION L TO CENTER OF LEAD WHEN FORMED PARALLEL.
  2. PACKAGE CONTOUR OPTIONAL (ROUND OR SQUARE CORNERS).

  3. DIMENSIONING AND TOLERANCING PER ANSI 744 54M 1982 Y14.5M, 1982.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
Α	9.40	10.16	0.370	0.400
В	6.10	6.60	0.240	0.260
С	3.94	4.45	0.155	0.175
D	0.38	0.51	0.015	0.020
F	1.02	1.78	0.040	0.070
G	2.54 BSC		0.100 BSC	
Н	0.76	1.27	0.030	0.050
J	0.20	0.30	0.008	0.012
K	2.92	3.43	0.115	0.135
L	7.62 BSC		0.300 BSC	
М		10°		10°
N	0.76	1.01	0.030	0.040





#### NOTES:

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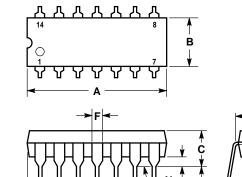
  1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
  2. DIMENSIONS ARE IN MILLIMETERS.
  3. DIMENSION D AND E DO NOT INCLUDE MOLD PROTRUSION.
  4. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
  5. DIMENSION B DOES NOT INCLUDE MOLD PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 TOTAL IN EXCESS OF THE B DIMENSION AT MAXIMUM MATERIAL OF THE B DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIMETERS			
DIM	MIN	MAX		
Α	1.35	1.75		
A1	0.10	0.25		
В	0.35	0.49		
С	0.18	0.25		
D	4.80	5.00		
E	3.80	4.00		
е	1.27	BSC		
Н	5.80	6.20		
h	0.25	0.50		
L	0.40	1.25		
θ	0°	7 °		

#### **OUTLINE DIMENSIONS**

#### **N SUFFIX**

PLASTIC PACKAGE CASE 646-06 ISSUE L



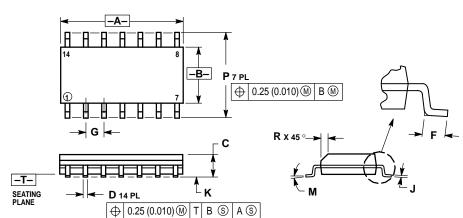
- NOTES:
  1. LEADS WITHIN 0.13 (0.005) RADIUS OF TRUE POSITION AT SEATING PLANE AT MAXIMUM MATERIAL CONDITION.

  2. DIMENSION L TO CENTER OF LEADS WHEN
- FORMED PARALLEL.
- 3. DIMENSION B DOES NOT INCLUDE MOLD FLASH.
- 4. ROUNDED CORNERS OPTIONAL.

	INCHES		MILLIN	METERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.715	0.770	18.16	19.56	
В	0.240	0.260	6.10	6.60	
С	0.145	0.185	3.69	4.69	
D	0.015	0.021	0.38	0.53	
F	0.040	0.070	1.02	1.78	
G	0.100 BSC		2.54 BSC		
Н	0.052	0.095	1.32	2.41	
J	0.008	0.015	0.20	0.38	
K	0.115	0.135	2.92	3.43	
L	0.300 BSC		7.62	BSC	
М	0°	10°	0°	10°	
N	0.015	0.039	0.39	1.01	



PLASTIC PACKAGE CASE 751A-03 (SO-14)**ISSUE** É



#### NOTES:

- NOTES:
  1 DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: MILLIMETER.
  3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
  4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) DEB SIGE.

- PER SIDE.
- PER SIDE.

  5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIMETERS		INC	HES
DIM	MIN	MAX	MIN	MAX
Α	8.55	8.75	0.337	0.344
В	3.80	4.00	0.150	0.157
С	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27	1.27 BSC		BSC
J	0.19	0.25	0.008	0.009
K	0.10	0.25	0.004	0.009
M	0 °	7°	0 °	7°
Р	5.80	6.20	0.228	0.244
R	0.25	0.50	0.010	0.019

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